

Bipolar Transistor

(–)50 V, (–)2 A, Low VCE(sat),
(PNP)NPN Single TP/TP-FA

2SB1201/2SD1801

Features

- Adoption of FBET, MBIT Processes
- Low Collector-to-Emitter Saturation Voltage
- Small and Slim Package Making it Easy to Make 2SB1201 / 2SD1801 – Used Sets Smaller
- Large Current Capacitance and Wide ASO
- These are Pb-Free Devices

Applications

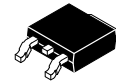
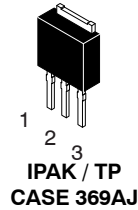
- Voltage Regulators, Relay Drivers, Lamp Drivers, Electrical Equipment

ABSOLUTE MAXIMUM RATINGS (at Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)60	V
Collector-to-Emitter Voltage	V _{CEO}		(–)50	V
Emitter-to-Base Voltage	V _{EBO}		(–)6	V
Collector Current	I _C		(–)2	A
Collector Current (Pulse)	I _{CP}		(–)4	A
Collector Dissipation	P _C		0.8	W
		T _C = 25°C	15	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

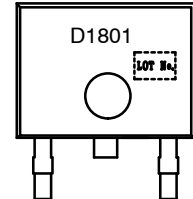
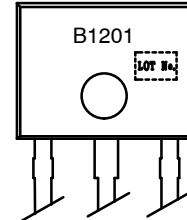
NOTE: Specifications (): 2SB1201



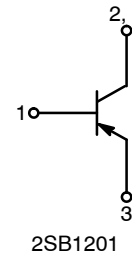
IPAK / TP
CASE 369AJ

DPAK / TP-FA
CASE 369AH

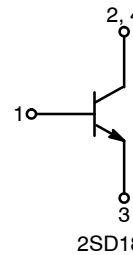
MARKING DIAGRAMS



ELECTRICAL CONNECTION



2SB1201



2SD1801

ORDERING INFORMATION

Device	Package	Shipping†
2SB1201S-E	IPAK / TP (Pb-Free)	500 pcs / Bag
2SB1201S-TL-E	DPAK / TP-FA (Pb-Free)	700 / Tape & Reel
2SB1201T-TL-E	DPAK / TP-FA (Pb-Free)	700 / Tape & Reel
2SD1801S-TL-E	DPAK / TP-FA (Pb-Free)	700 / Tape & Reel
2SD1801S-E	IPAK / TP (Pb-Free)	500 pcs / Bag

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

2SB1201/2SD1801

ELECTRICAL CHARACTERISTICS (at Ta = 25°C)

Parameter	Symbol	Conditions	Ratings			Unit
			Min	Typ	Max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)50\text{ V}, I_E = 0\text{ A}$	–	–	(–)100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4\text{ V}, I_C = 0\text{ A}$	–	–	(–)100	nA
DC Current Gain	h_{FE1}	$V_{CE} = (-)2\text{ V}, I_C = (-)100\text{ mA}$	100*	–	560*	–
	h_{FE2}	$V_{CE} = (-)2\text{ V}, I_C = (-)1.5\text{ A}$	40	–	–	–
Gain–Bandwidth Product	f_T	$V_{CE} = (-)10\text{ V}, I_C = (-)50\text{ mA}$	–	150	–	MHz
Output Capacitance	C_{ob}	$V_{CB} = (-)10\text{ V}, f = 1\text{ MHz}$	–	(22)12	–	pF
Collector–to–Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)1\text{ A}, I_B = (-)50\text{ mA}$	–	(–0.3)0.15	(–0.7)0.4	V
Base–to–Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)1\text{ A}, I_E = (-)50\text{ mA}$	–	(–)0.9	(–)1.2	V
Collector–to–Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\text{ }\mu\text{A}, I_E = 0\text{ A}$	(–)60	–	–	V
Collector–to–Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1\text{ mA}, R_{BE} = \infty$	(–)50	–	–	V
Emitter–to–Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\text{ }\mu\text{A}, I_C = 0\text{ A}$	(–)6	–	–	V
Turn–ON Time	t_{on}	See specified Test Circuit.	–	(60)60	–	ns
Storage Time	t_{stg}		–	(450)550	–	ns
Fall Time	t_f		–	30	–	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTE: Specifications (): 2SB1201

*The 2SB1201 / 2SD1801 are classified by 100 mA h_{FE} as follows :

Table 1.

Rank	R	S	T	U
h_{FE}	100 to 200	140 to 280	200 to 400	280 to 560

Switching Time Test Circuit

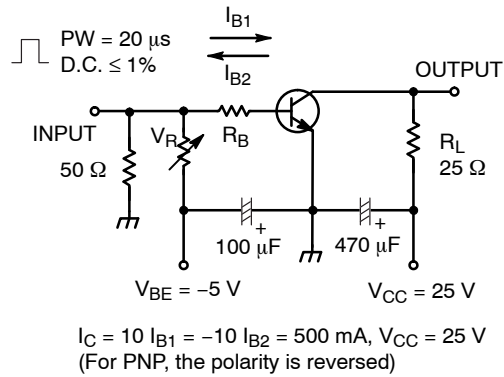


Figure 1. Switching Time Test Circuit

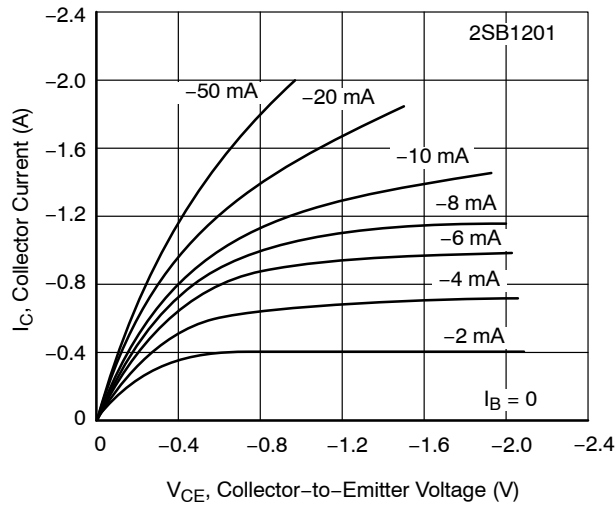


Figure 2. $I_C - V_{CE}$

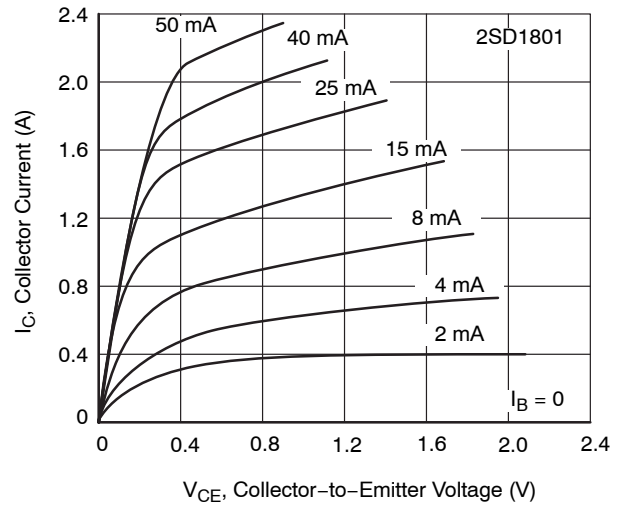


Figure 3. $I_C - V_{CE}$

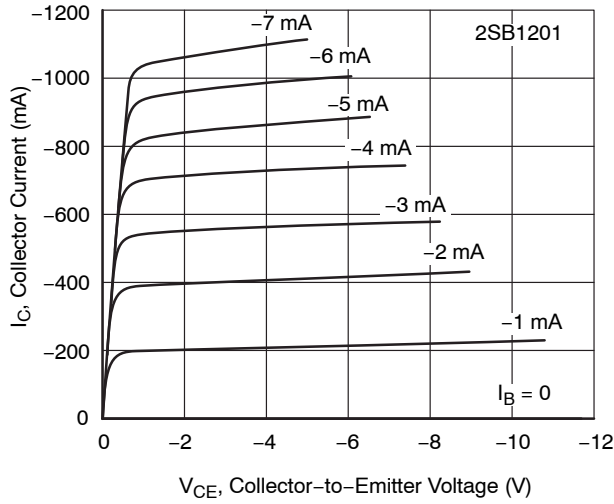


Figure 4. $I_C - V_{CE}$

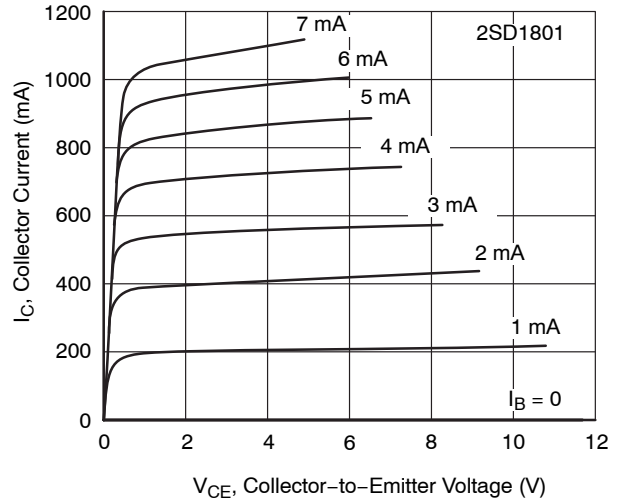


Figure 5. $I_C - V_{CE}$

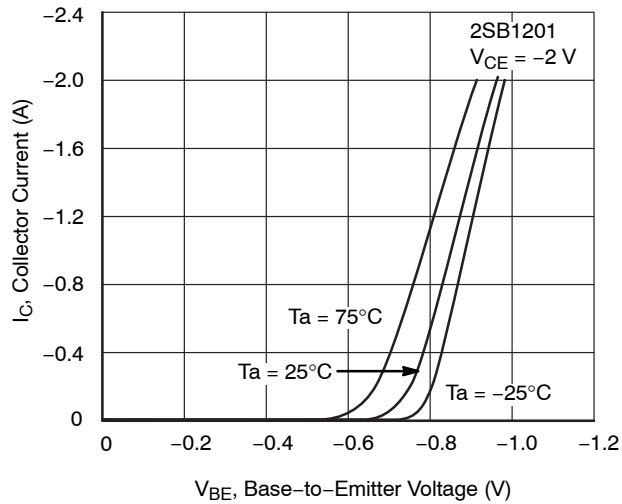


Figure 6. $I_C - V_{BE}$

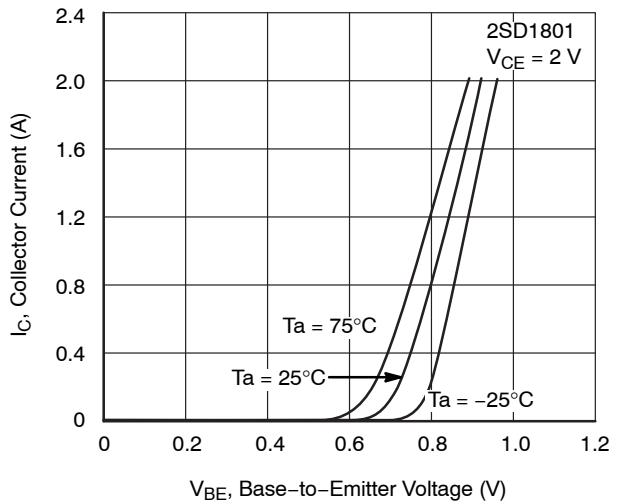


Figure 7. $I_C - V_{BE}$

2SB1201/2SD1801

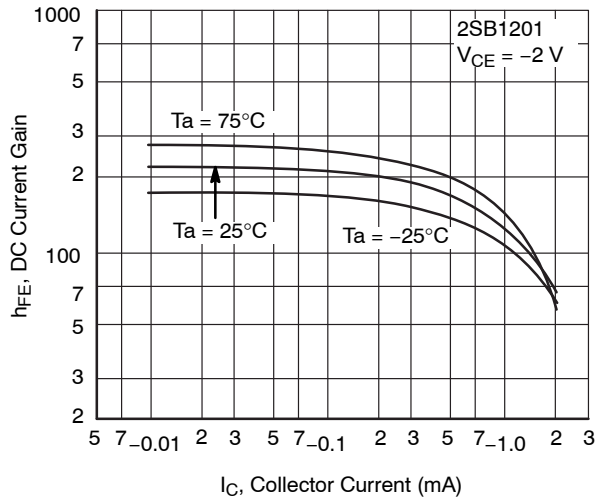


Figure 8. $h_{FE} - I_C$

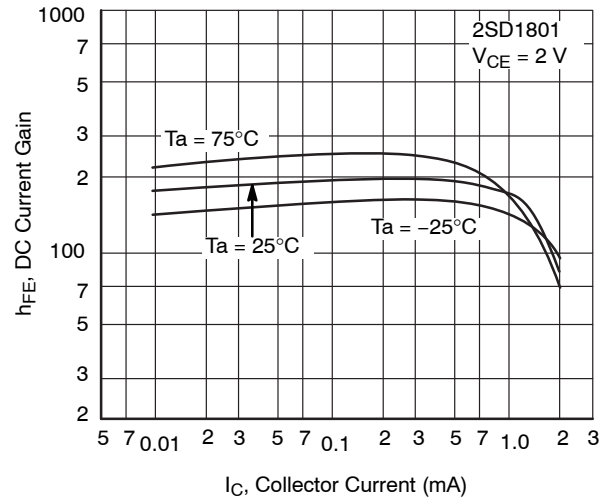


Figure 9. $h_{FE} - I_C$

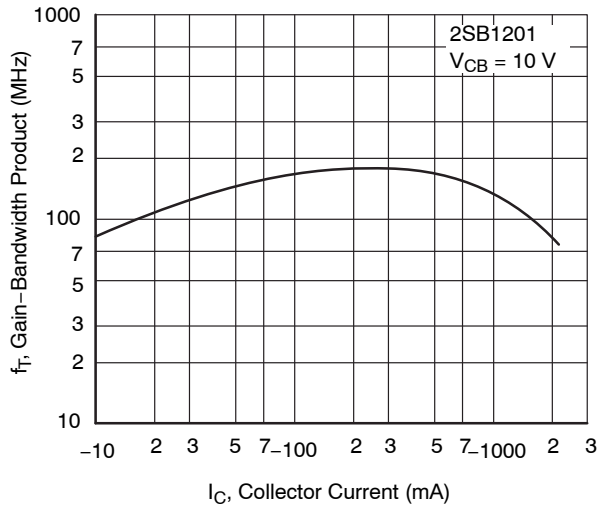


Figure 10. $f_T - I_C$

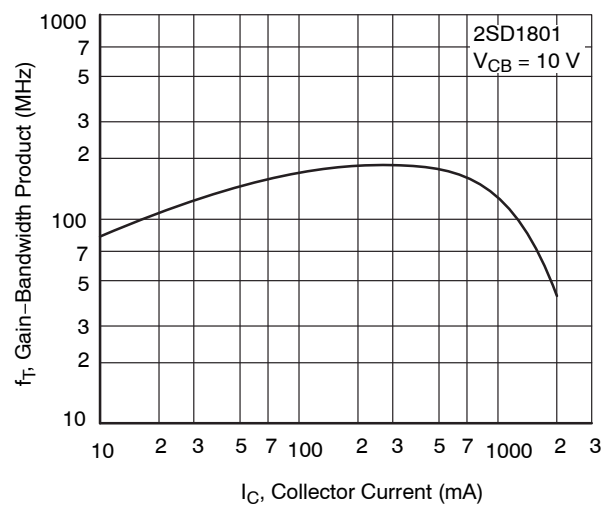


Figure 11. $f_T - I_C$

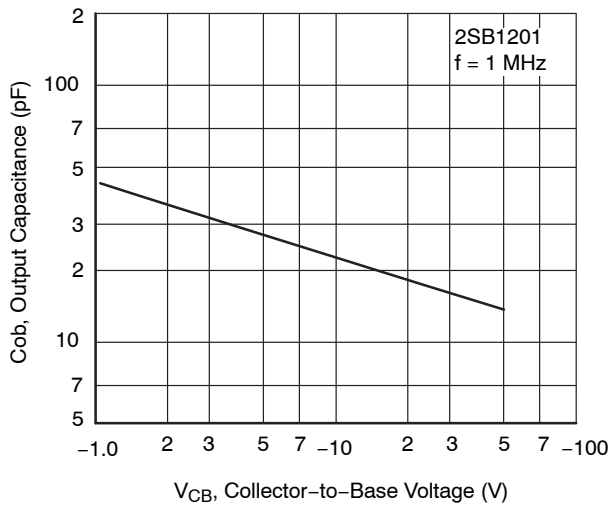


Figure 12. $C_{ob} - V_{CB}$

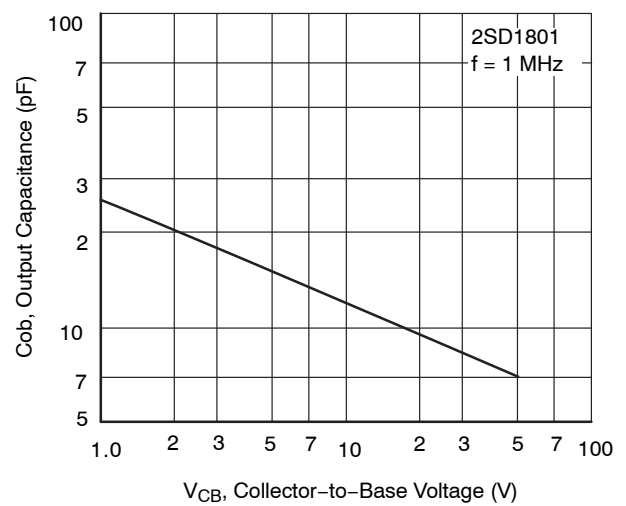


Figure 13. $C_{ob} - V_{CB}$

2SB1201/2SD1801

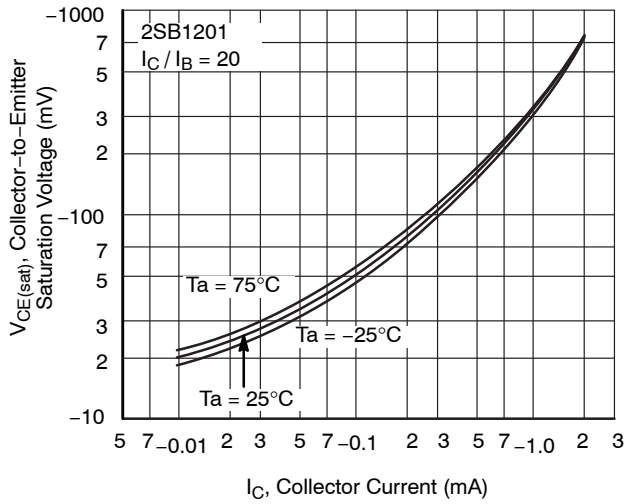


Figure 14. $V_{CE(sat)} - I_C$

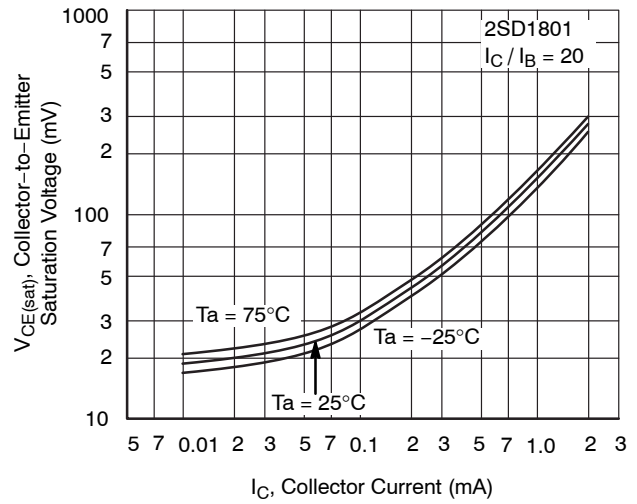


Figure 15. $V_{CE(sat)} - I_C$

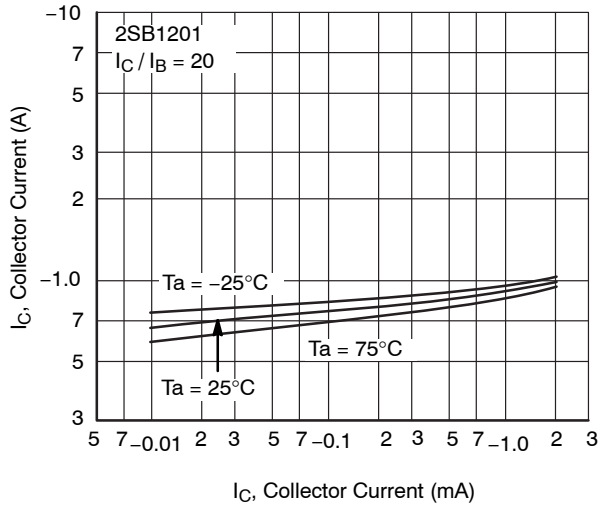


Figure 16. $V_{BE(sat)} - I_C$

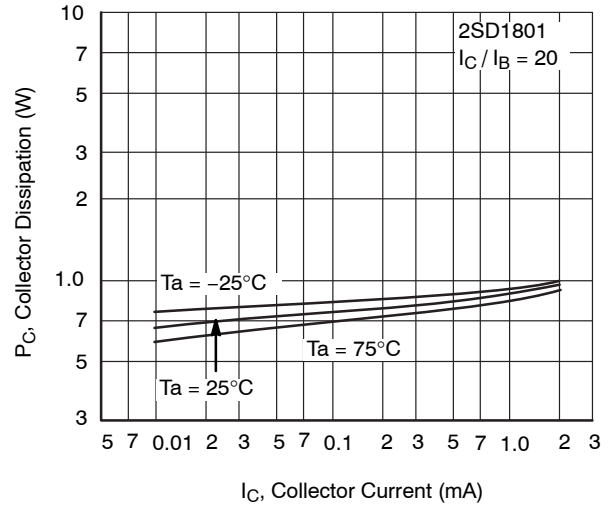


Figure 17. $V_{BE(sat)} - I_C$

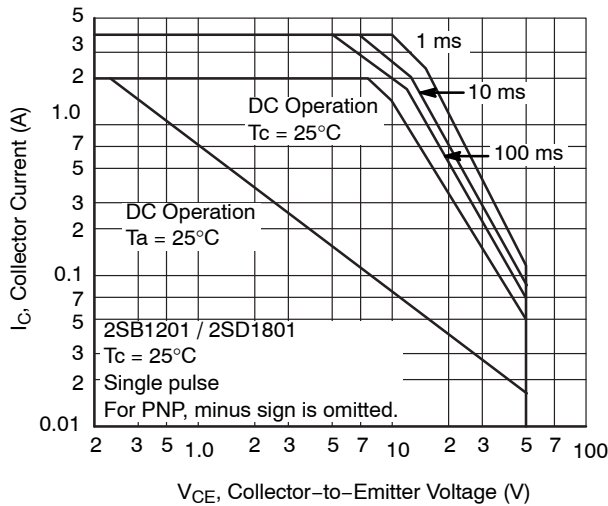


Figure 18. ASO

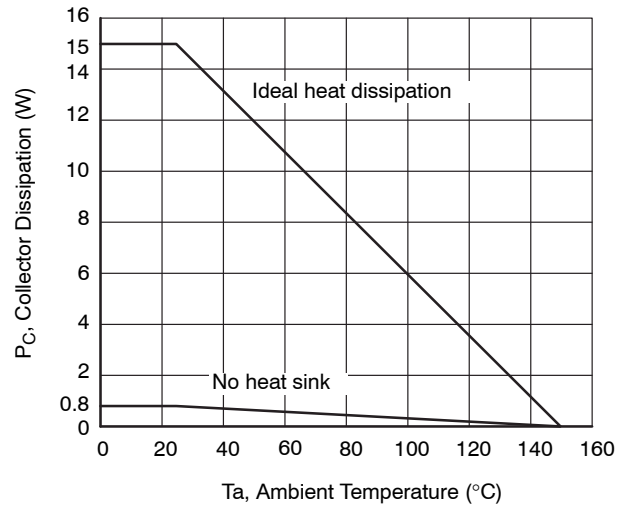


Figure 19. $P_C - T_a$

MECHANICAL CASE OUTLINE

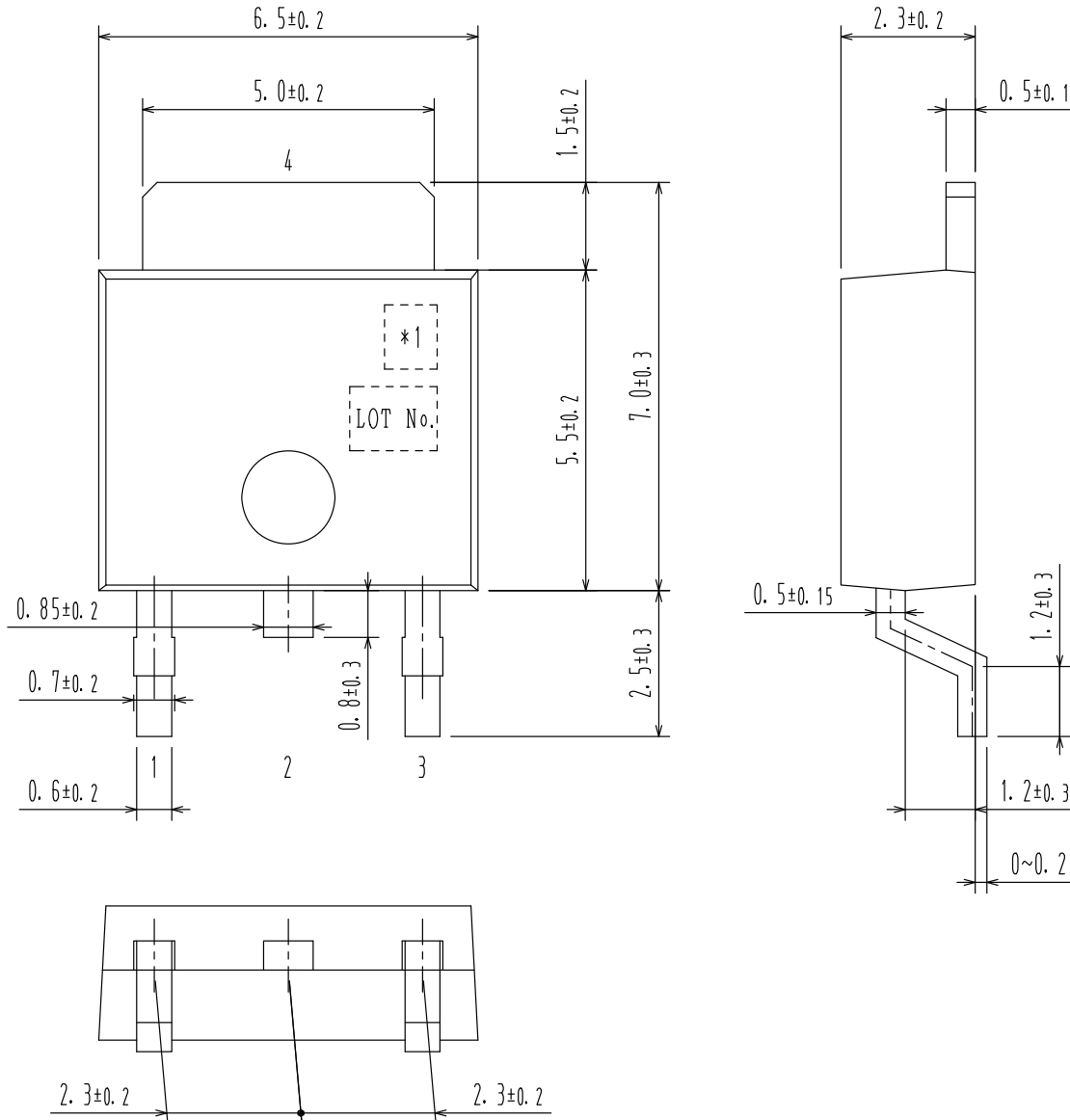
PACKAGE DIMENSIONS

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DKPAK / TP-FA
CASE 369AH
ISSUE O

DATE 30 JAN 2012



Pin 2 is idle pin with electrical designation only carried.

1:
2:
3:
*1: Lot indication 4:

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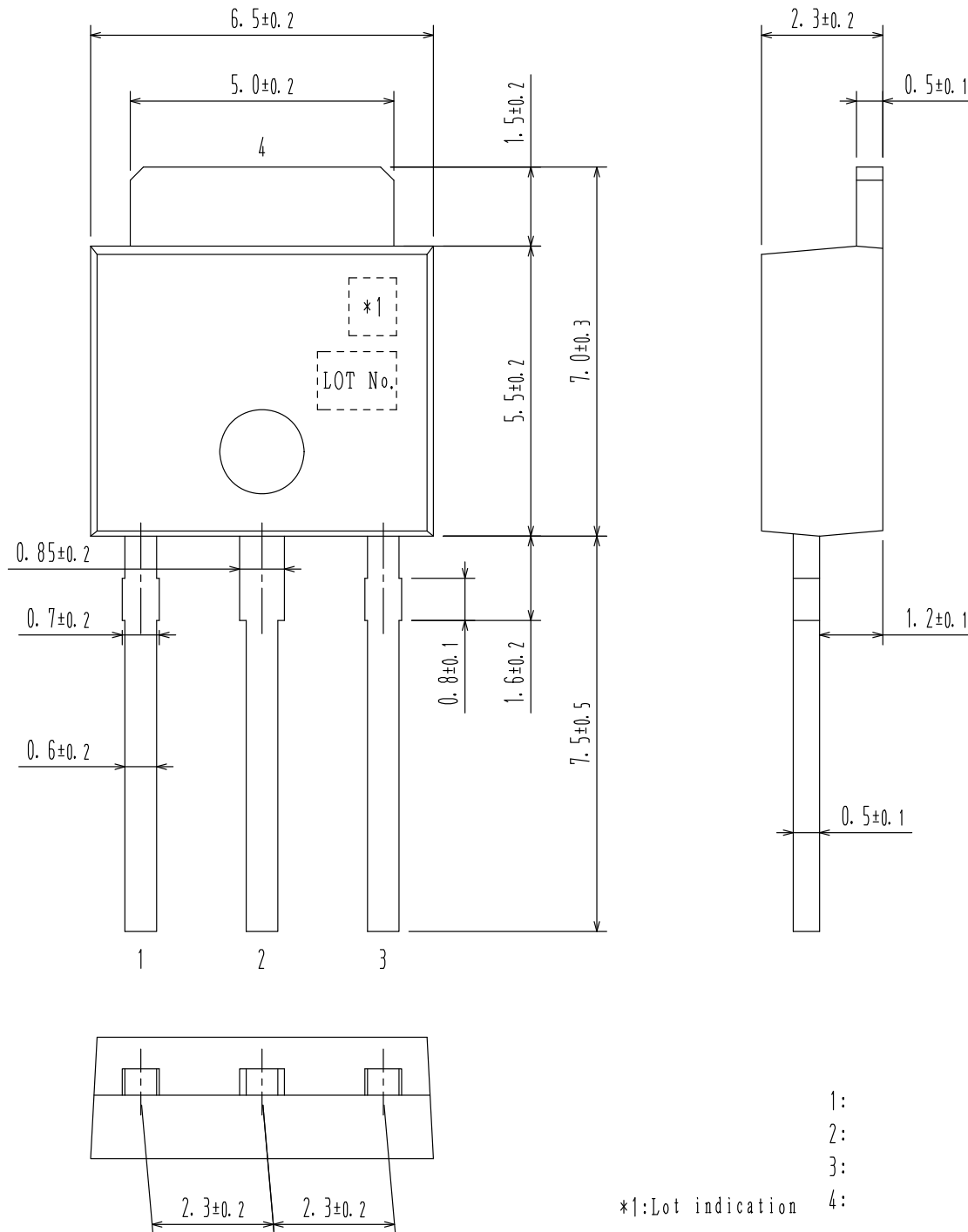
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